

## SMAG Plastic-Encapsulate Diodes

### SS12 THRU SS120 Schottky Rectifier Diodes

#### Features

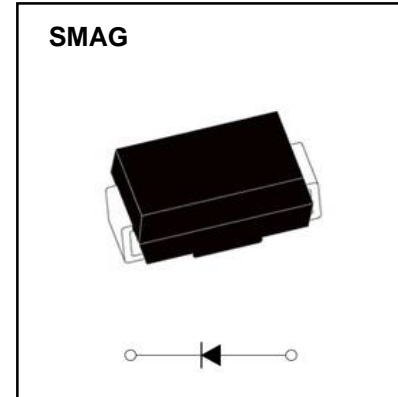
- $I_{F(AV)}$  1A
- $V_{RRM}$  20V-200V
- High surge current capability
- Polarity: Color band denotes cathode

#### Applications

- Rectifier

#### Marking

- SS1X  
X : From 2 To 20



#### Limiting Values(Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	SS1																	
				2	3	4	5	6	8	10	15	20									
Repetitive Peak Reverse Voltage	$V_{RRM}$	V		20	30	40	50	60	80	100	150	200									
Maximum RMS Voltage	$V_{RMS}$	V		14	21	28	35	42	56	70	105	140									
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load, FIG.1	1.0																	
Surge(Non-repetitive)Forward Current	$I_{FSM}$	A	60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	30																	
Junction Temperature	$T_J$	$^\circ\text{C}$		-55~+125					-55~+150												
Storage Temperature	$T_{STG}$	$^\circ\text{C}$		-55 ~ +150																	

#### Electrical Characteristics ( $T = 25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	SS1																
				2	3	4	5	6	8	10	15	20								
Peak Forward Voltage	$V_F$	V	$I_F=1.0\text{A}$	0.55		0.70		0.85		0.95										
Peak Reverse Current	$I_{RRM1}$	mA	$V_{RM}=V_{RRM}$	$T_a=25^\circ\text{C}$		0.5		0.1												
	$I_{RRM2}$			$T_a=100^\circ\text{C}$		10		5.0												
Thermal Resistance(Typical)	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	Between junction and ambient	65																
	$R_{\theta J-L}$		Between junction and terminal	20																

#### Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

# Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

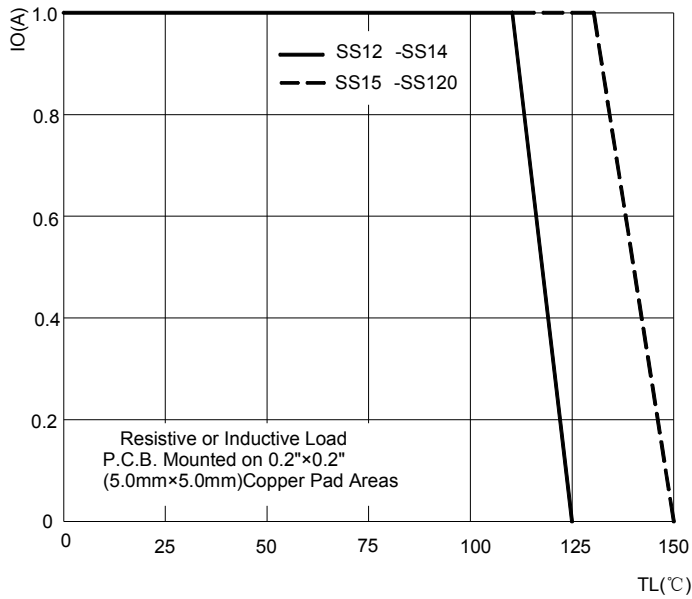


FIG2: Surge Forward Current Capacity

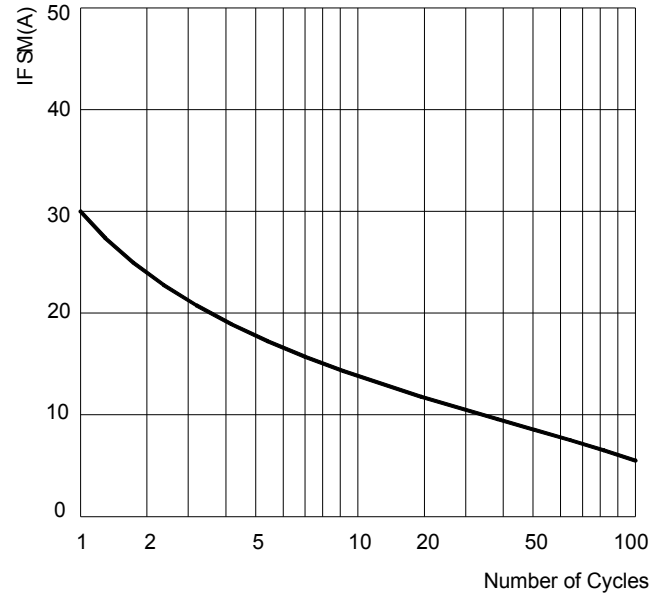


FIG.3: TYPICAL FORWARD CHARACTERISTICS

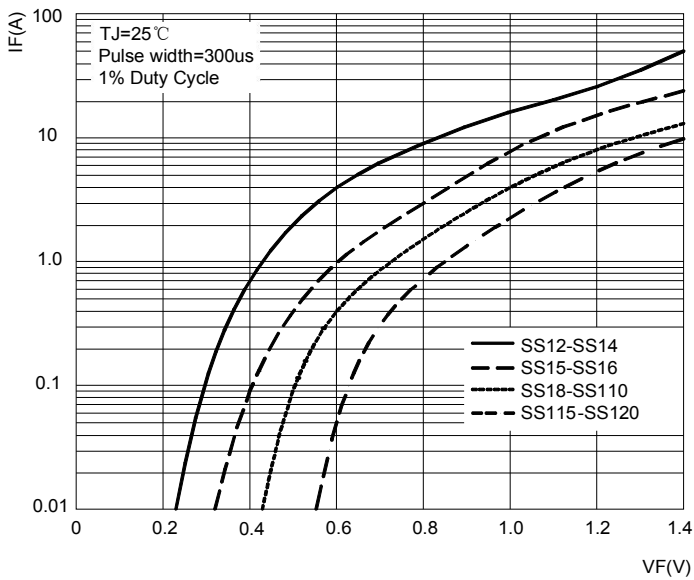
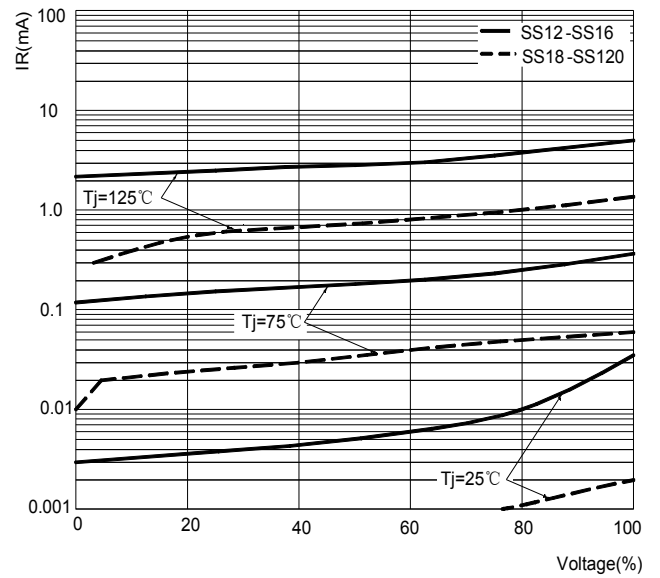
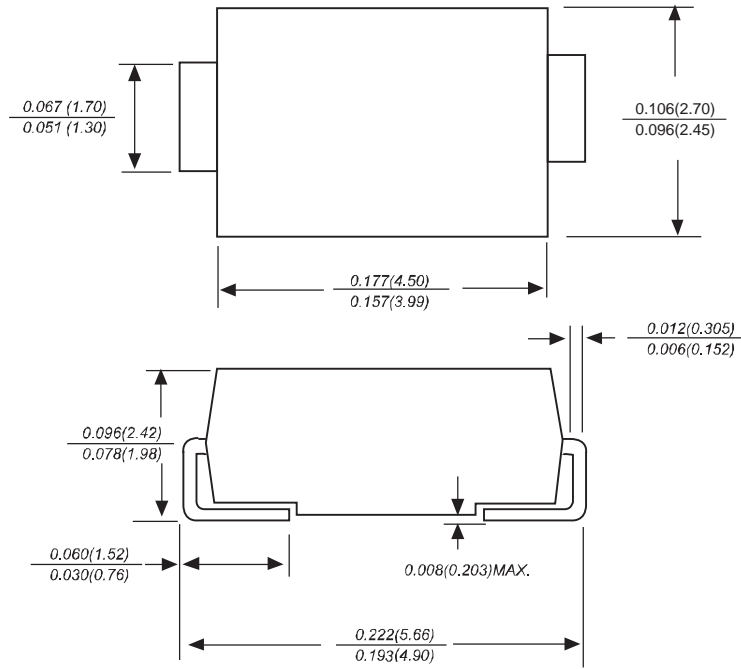


FIG.4: TYPICAL REVERSE CHARACTERISTICS

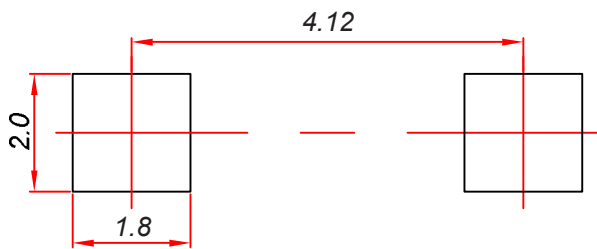


## SMAG Package Outline Dimensions



Dimensions in inches and (millimeters)

## SMAG Suggested Pad Layout



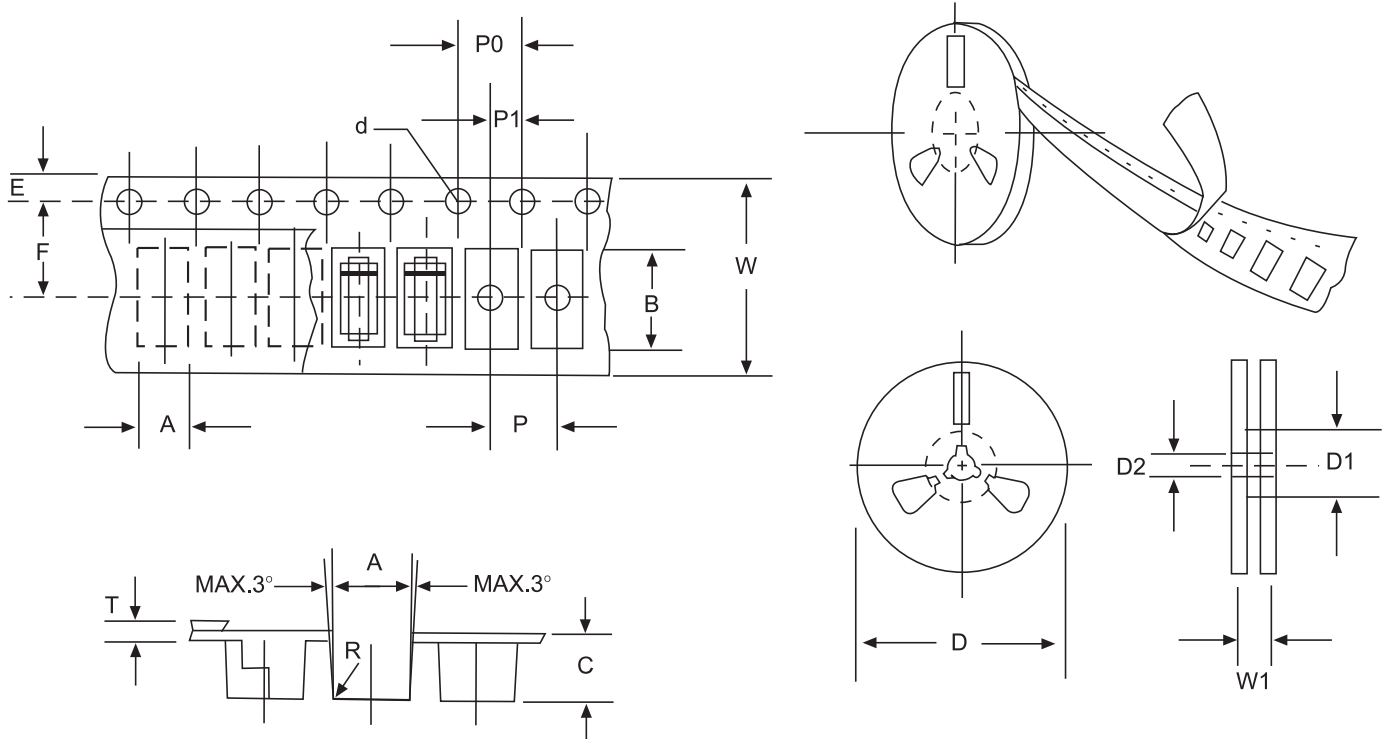
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$  mm.
3. The pad layout is for reference purposes only.

### NOTICE

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## Reel Taping Specifications For Surface Mount Devices- SMAG



**FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING**

ITEM	SYMBOL	SMAG mm(inch)
Carrier width	A	2.79±0.1(0.110±0.004)
Carrier length	B	5.33±0.1(0.210±0.004)
Carrier depth	C	2.36±0.1(0.093±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	279±2.0 (11± 0.079)
Reel inner diameter	D1	75 ±1.0 ( 2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Sprocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.5±0.05(0.217±0.002)
Punch hole pitch	P	4.0±0.1(0.157±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Totall tape thickness	T	0.28±0.02(0.011 ±0.0008)
Tape width	W	12.0±0.2(0.472±0.008)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.